

Final Product/Process Change Notification

Document #:FPCN22880X Issue Date:29 Oct 2019

Title of Change:	Process change fix	ix for AR0521 to prevent static induced defects.					
Proposed First Ship date:	05 Feb 2020 or ea	rlier if approved by customer					
Contact Information:	Contact your local	ON Semiconductor Sales Office or <geethakrishnan.narasimhan@onsemi.com></geethakrishnan.narasimhan@onsemi.com>					
PCN Samples Contact:	Contact your local ON Semiconductor Sales Office or <pcn.samples@onsemi.com>. Sample requests are to be submitted no later than 30 days from the date of first notification, Initial PCN or Final PCN, for this change. Samples delivery timing will be subject to request date, sample quantity and special customer packing/label requirements.</pcn.samples@onsemi.com>						
Additional Reliability Data:	Contact your local ON Semiconductor Sales Office or Amy.Wu@onsemi.com						
Type of Notification:	days prior to imple ON Semiconducto	oduct/Process Change Notification (FPCN) sent to customers. FPCNs are issued 90 plementation of the change. tor will consider this change accepted, unless an inquiry is made in writing within 30 of this notice. To do so, contact PCN.Support@onsemi.com					
Marking of Parts/ Traceability of Change:	Date code beginni	ng 1st week of Feb 2020					
Change Category:	Wafer Fab Change	ge					
Change Sub-Category(s):	Manufacturing Pro	rocess Change					
Sites Affected:							
ON Semiconductor Sites		External Foundry/Subcon Sites					
None		TSMC Semiconductor, Taiwan					

Description and Purpose:

The anti-reflective dielectric film above the image sensor array is being changed to a higher dielectric constant foundry proprietary film along with a UV cure. The purpose is to prevent any damage to the sensor array from static charges during subsequent processing in assembly or install in a module

There is no change to BOM, form, fit or function of the product. There is no product marking change as a result of this change.

Units with the proposed process change will be identified with a date code beginning 1st week of Feb 2020.

	Before Change Description	After Change Description					
Other Changes	Anti-reflective Dielectric Film above image sensor array	Foundry proprietary anti-reflective higher dielectric constant film and UV curing					

There are no product marking changes as a result of this change.

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Reliability Data Summary:

QV DEVICE NAME: AR0522 PACKAGE : mPLCC

Test	Specification	Condition	Interval	Results		
HTOL	JESD22-A108	Ta=105°C, 100 % max rated Vcc	1008 hrs	0/240		
HTSL	JESD22-A103	Ta= 150°C	1008 hrs	0/80		
TC	JESD22-A104	Ta= -55°C to +125°C	1000 cyc	0/120		
THB	JESD22-A101D	85°C/ 85% RH, with bias	1008 hrs	0/80		
PC	J-STD-020 JESD-A113	MSL 4 @ 260 °C		Pass		
HBM	JESD22-A114	HBM 2KV		0/3		
CDM	JESD22-C101	CDM 500V		0/3		
LU	JESD78	LU 1.5Vcc		0/6		
SD	JSTD002	Method S1		0/45		

Electrical Characteristics Summary:

Electrical Characteristics are not impacted. All parameters are within spec and comparable to current baseline. See Table below.

30 samples pe	rlot			Lo	t1					Lo	t2					Lot	3			
Temp: 60C (as per DS)		Avg (POR)	Avg (New)	Sig (POR)	Sig (New)	CPK (POR)	CPK (New)	Avg (POR)	Avg (New)	Sig (POR)	8	CPK (POR)	CPK (New)	-	Avg (New)	Sig (POR)	Sig (New)		CPK (New)	Uni
SoftStby	IDD-IO:	0.052	0.051	0.001	0.001	7.97	6.59	0.052	0.051	0.001	0.001	9.99	8.80	0.053	0.052	0.001	0.001	8.58	8.94	mA
,	IDD:	2.178	2.207	0.043	0.060	11.67	8.36	2.189	2.205	0.029	0.056	17.13	8.93	2.210	2.154	0.049	0.043	10.16	12.07	mA
(clkON)	IAA:	0.066	0.066	0.001	0.001	12.21	12.70	0.066	0.066	0.001	0.002	13.14	10.72	0.066	0.066	0.002	0.001	10.27	13.42	. mA
C - fresh	IDD-IO:	0.028	0.028	0.002	0.002	1.31	1.35	0.028	0.028	0.002	0.002	1.45	1.52	0.028	0.028	0.002	0.002	1.34	1.38	mA
SoftStby	IDD:	0.235	0.261	0.032	0.045	5.83	4.01	0.245	0.266	0.027	0.032	6.74	5.51	0.285	0.230	0.040	0.031	4.31	6.16	mΑ
(clkOFF)	IAA:	0.064	0.064	0.001	0.001	13.05	13.51	0.064	0.064	0.001	0.002	13.91	11.64	0.064	0.064	0.002	0.001	11.10	14.60	mΑ
	IDD-IO:	0.054	0.054	0.001	0.002	4.13	3.55	0.054	0.054	0.001	0.001	5.15	4.70	0.056	0.055	0.001	0.001	4 22	4.73	- A
HardStby	IDD-IO.	0.034	0.604		0.002	10.21	6.89		0.608	0.001	0.001		9.04	0.056 0.627	0.055	0.001	0.001	4.33 7.70		_
(clkON)	IAA:	0.005	0.004		0.001	3.18	3.69		0.005	0.001	0.040	3.18	3.24		0.005	0.040	0.001	3.25	3.35	_
HardStby	IDD-IO:	0.036	0.035	0.002	0.002	5.22	4.87	0.035	0.035	0.002	0.002	5.45	5.54	0.036	0.035	0.002	0.002	5.27	5.07	mΑ
(clkOFF)	IDD:	0.247	0.274	0.034	0.048	5.39	3.67	0.257	0.279	0.029	0.034	6.20	5.04	0.300	0.241	0.042	0.033	3.94	5.68	m/
(CIKOTT)	IAA:	0.002	0.002	0.000	0.000	8.97	10.23	0.002	0.002	0.000	0.000	9.29	9.31	0.002	0.002	0.000	0.000	9.15	9.98	mA
Operating current	IDD-IO:	0.057	0.057	0.004	0.005	5.74	4.36	0.056	0.055	0.004	0.004	5.81	5.59	0.057	0.057	0.003	0.004	6.17	5.64	m/
5M full resolution	IDD:	93.33	93.23			5.05	5.94		93.13	1.86			5.47	91.58	92.40	1.74				_
12 bit Linear 30fps	IAA:	69.32	68.46	3.34	3.39	3.36	3.40	69.46	68.72	3.65	2.94	3.06	3.88	68.39	69.24	3.45	3.50	3.34	3.22	mA

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List of Affected Parts:

Note: Only the standard (off the shelf) part numbers are listed in the parts list. Any custom parts affected by this PCN are shown in the customer specific PCN addendum in the PCN email notification, or on the <u>PCN Customized Portal</u>.

Part Number	Qualification Vehicle						
AR0521SR2M09SURA0-DR1	AR0521SR2C09SURA0-DP						
AR0521SR2M09SURA0-DR	AR0521SR2C09SURA0-DP						
AR0521SR2M09SURA0-DP1	AR0521SR2C09SURA0-DP						
AR0521SR2M09SURAO-DP	AR0521SR2C09SURA0-DP						
AR0521SR2C09SURA0-DR1	AR0521SR2C09SURA0-DP						
AR0521SR2C09SURA0-DR	AR0521SR2C09SURA0-DP						
AR0521SR2C09SURA0-DP1	AR0521SR2C09SURA0-DP						
AR0521SR2C09SURAO-DP	AR0521SR2C09SURA0-DP						

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